





200V PNP MEDIUM POWER HIGH GAIN TRANSISTOR IN E-LINE

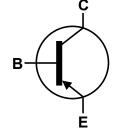
Features

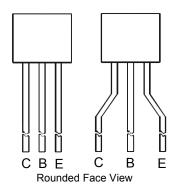
- BV_{CEO} > -200V
- I_C = -0.5A High Continuous Collector Current
- I_{CM} = -1A Peak Pulse Current
- T_J up to 200°C for High Temperature Operation
- h_{FE} > 250 @ 0.3A for High Gain Hold-Up
- P_D = 1W Power dissipation
- Complementary NPN Type: ZTX696B
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

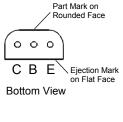
Mechanical Data

- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.159 grams (approximate)









Flat Face View

Device Symbol

Pin-Out Configuration

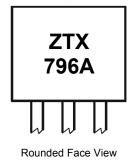
Ordering Information (Note 4)

Product	Marking	Package	Leads	Quantity
ZTX796ASTZ	ZTX796A	E-Line	Joggled	2,000 Taped per Ammo Box
ZTX796A	ZTX796A	E-Line	Straight	4,000 Loose in a Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZTX796A = Product Type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	-200	V	
Collector-Emitter Voltage	V _{CEO}	-200	V	
Emitter-Base Voltage	V _{EBO}	-5	V	
Continuous Collector Current	I _C	-0.5	A	
Peak Pulse Current	I _{CM}	-1	Α	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1.5	W
Power Dissipation (Note 6)	P _D	1	W
Thermal Resistance Junction to Ambient (Note 5)	$R_{ heta JA}$	116	°C/W
Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	175	°C/W
Thermal Resistance Junction to Lead (Note 7)	$R_{ heta JL}$	70	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +200	°C

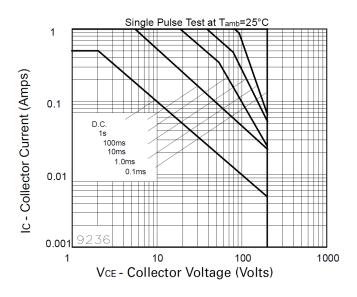
Notes:

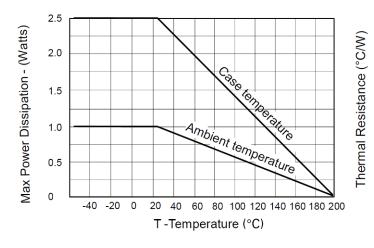
- 5. For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
 7. Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).

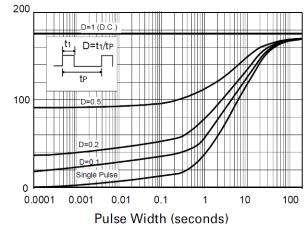




Thermal Characteristics and Derating Information







Derating curve

Maximum transient thermal impedance





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-200	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-200	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -100μA
Collector-Emitter Cutoff Current	I _{CES}	_	_	-0.1	μA	V _{CE} = -150V
Collector-Base Cutoff Current	I _{CBO}	_	_	-0.1	μA	V _{CB} = -150V
Emitter-Base Cutoff Current	I _{EBO}	_	_	-0.1	μA	V _{EB} = -4V
Collector Facilitae Catamatica Voltage (Nata 7)	.,	_	_	-0.2	mV	I _C = -50mA, I _B = -2mA
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	_	-0.3 -0.3	mV mV	I_C = -100mA, I_B = -5mA I_C = -200mA, I_B = -20mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	_	-0.95	mV	I _C = -200mA, I _B = -20mA
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	_	-0.67	_	mV	I _C = -200mA, V _{CE} = -10V
Static Forward Current Transfer Ratio (Note 7)	h _{FE}	300 300 250 100	_ _ _ _	800 — — —	_ _ _ _	I _C = -10mA, V _{CE} = -10V I _C = -100mA, V _{CE} = -10V I _C = -300mA, V _{CE} = -10V I _C = -400mA, V _{CE} = -10V
Transition Frequency	f⊤	100	_	_	MHz	$V_{CE} = -5V, I_{C} = -50mA$ f = 50MHz
Input Capacitance	C _{ibo}	_	225	_	pF	V _{EB} = -0.5V, f = 1MHz
Output Capacitance	C _{obo}	_	12	_	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on}	_	100	_	ns	V _{CC} = -50V, I _C = -100mA
Switching Times	t _{off}	_	3200	_	ns	$I_{B1} = -I_{B2} = -10 \text{mA}$

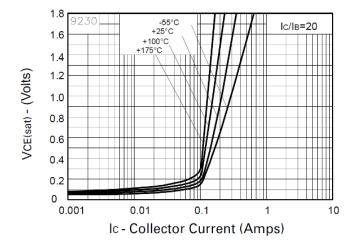
Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

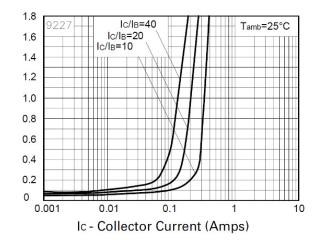


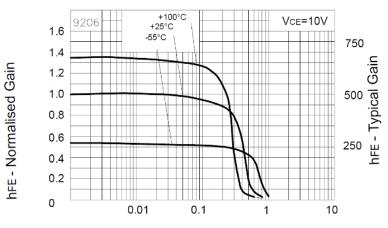


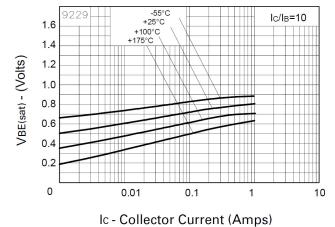
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

VCE(sat) - (Volts)

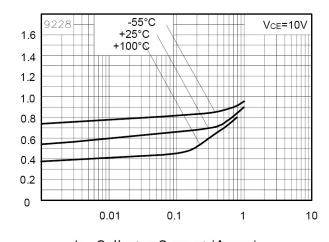








Ic - Collector Current (Amps)



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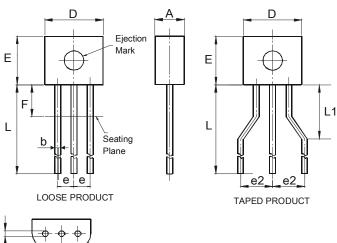
VBE - (Volts)





Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



E-Line					
Dim	Min	Max	Тур		
Α	2.16	2.41	_		
b	0.41	0.495	_		
b1	0.41	0.495	_		
D	4.37	4.77	_		
E	3.61	4.01	_		
е	_	_	1.27		
e2	_	_	2.54		
F	_	2.50	_		
L	13.00	13.97	_		
L1	2.50	3.50	_		
All Dimensions in mm					



For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals. Note:





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